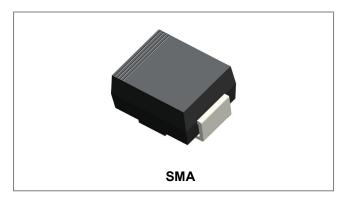


RoHS



UA1A-UA1M Ultrafast Avalanche Diodes



Features

- Ideally Suited for Automatic Assembly
- Low Forward Overload Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Material has UL Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Weight: 0.06 grams(approx)

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	UA1A	UA1B	UA1D	UA1G	UA1J	UA1K	UA1M	Units
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Surge Peak Reverse Voltage	V _{RSM}	50	100	200	400	600	800	1000	V
Max. Average Forward Current @T∟ =100°C	I _F				1.0				Α
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30			А				
Maximum Forward voltage @IF =1.0A	VF		1		1.25		1.7		V
Maximum Leakage Current @T _A = 25°C	I _R				3				μA
Reverse Recovery Time (Note 1)	Trr		50)			75		ns
Max. thermal resistance junction to ambient (Note 2)	R _{ΘJA}	70		K/W					
Non-Repetitive Avalanche Energy(Note 3)	E _{AS}				20				mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150			°C				

Note: 1. Measured with I_F=0.5A, I_R=1.0A, I_{rr}=0.25A

- 2. Mounted on P.C. Board with 8.0mm² lead area
- 3. $T_J = 25^{\circ}C$, $I_{AS}=1.0mA$, L=285mH
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Ratings and Characteristics Curves

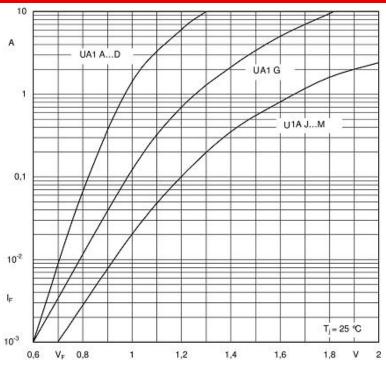


Fig. 1 Forward characteristics (typical values)

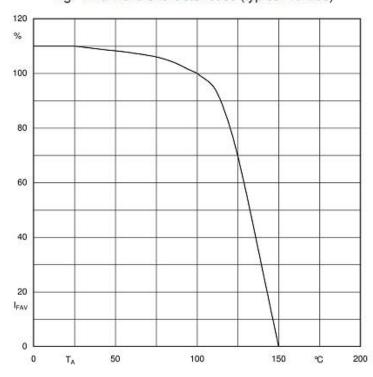


Fig. 2 Rated forward current vs. temp. of the terminals⁴)

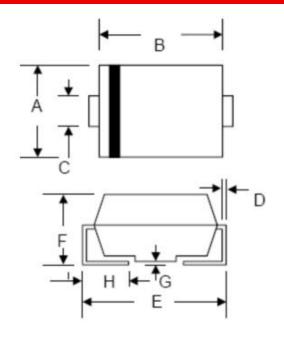
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Mechanical Dimensions SMA



CVMDOL	Milli	meters	Inches			
SYMBOL	Min.	Max.	Min.	Max.		
Α	2.40	2.84	0.094	0.112		
В	3.99	4.75	0.157	0.187		
С	1.05	1.70	0.041	0.067		
D	0.15	0.51	0.006	0.020		
E	4.80	5.66	0.189	0.223		
F	1.90	2.95	0.075	0.116		
G	0.05	0.203	0.002	0.008		
Н	0.76	1.52	0.030	0.600		

Ordering Information

Device	Package	Shipping		
UA1A-UA1M	SMA (Pb-Free)	5000pcs / reel		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



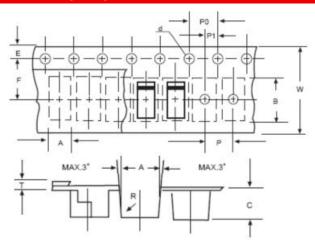
Where XXXXX is YYWWL

UA = Device Type 1 = Forward Current (1A) A = Reverse Voltage (50V)

YY = Year WW = Week L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Carrier Tape Specification SMA



SYMBOL	Millimeters			
	Min.	Max.		
Α	2.97	3.17		
В	5.70	5.90		
С	2.32	2.52		
d	1.40	1.60		
E	1.40	1.60		
F	5.60	5.70		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
Т	0.25	0.35		
W	11.80	12.20		

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